

Tuning van der Waals heterostructures by pressure

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In van der Waals heterostructures the layer distance strongly affects the interaction between the layers. Therefore, pressure is an ideal tool to engineer the band structure of van der Waal materials [1].

In this talk I will show two examples for the versatility of this method. First, I will show, that in WSe₂/Gr structures spin-orbit coupling can be induced in graphene using proximity effects, which can be boosted using hydrostatic pressure [2]. The enhancement is confirmed using weak anti-localization measurements. Moreover, I will also demonstrate the band structure tuning of magic-angle twisted double bilayer graphene [3]. We have performed thermal activation and magneto-transport measurements to reveal changes in the bandgaps of the system. We have observed a strong tuneability with pressure, which is confirmed by our theoretical calculations. Finally, we have also observed changes in the strength of electron-electron interactions and in the topological phases at the charge neutrality point in magnetic fields.

References

[1] B. Fülöp et al., Journal of Appl. Phys., 130 (2021), 064303

[2] B. Fülöp, A. Márffy, S. Zihlmann, M. Gmitra, E. Tóvári, B. Szentpéteri, M. Kedves, K. Watanabe, T. Taniguchi, J. Fabian, C. Schönenberger, P. Makk, Sz. Csonka, npj 2D Materials and Applications 5 (2021), 82

[3] B. Szentpéteri, P. Rickhaus, F. K. de Vries, A. Márffy, B. Fülöp, E. Tóvári, K. Watanabe, T. Taniguchi, A. Kormányos, Sz. Csonka, and P. Makk, Nano Letters, 21 (2021), 8777

Figures

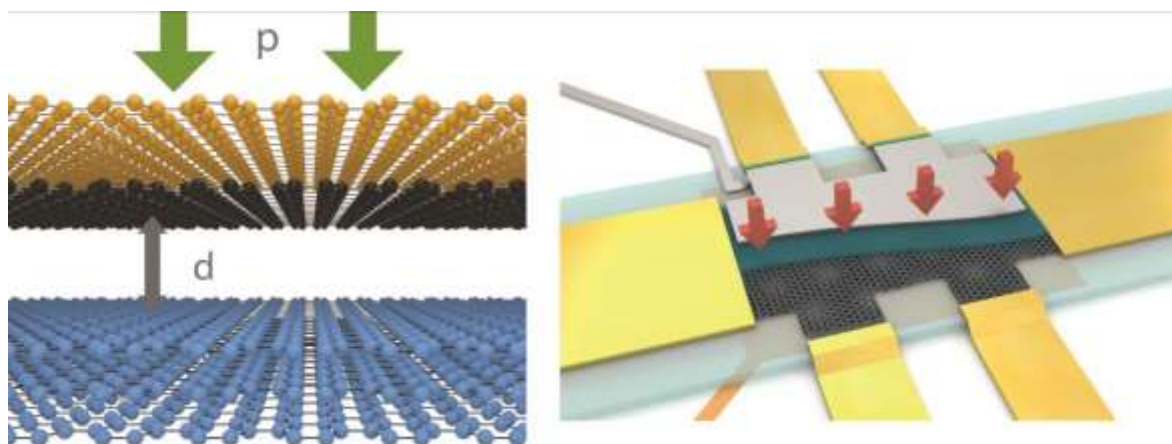


Figure 1: Illustration of the working principle of our pressure cell and an artistic view of the device architecture at study.